



Peak pulse voltage ( $T_j=25$ ; non-repetitive, off-state; FIG.8)	$V_{pp}$	2.5	kV
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ELECTRICAL CHARACTERISTICS (unless otherwise specified)

**Symbol**      **Test Condition**      **Quadrant**





**FIG.7:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

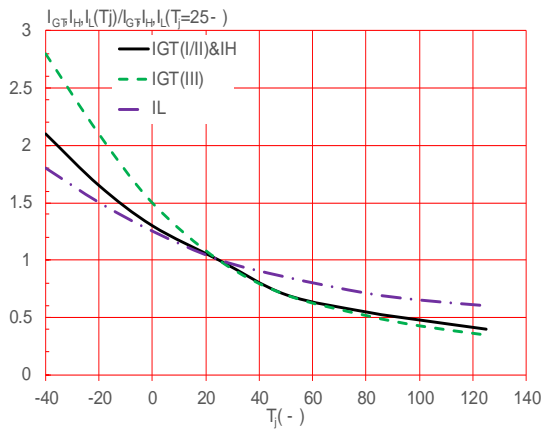
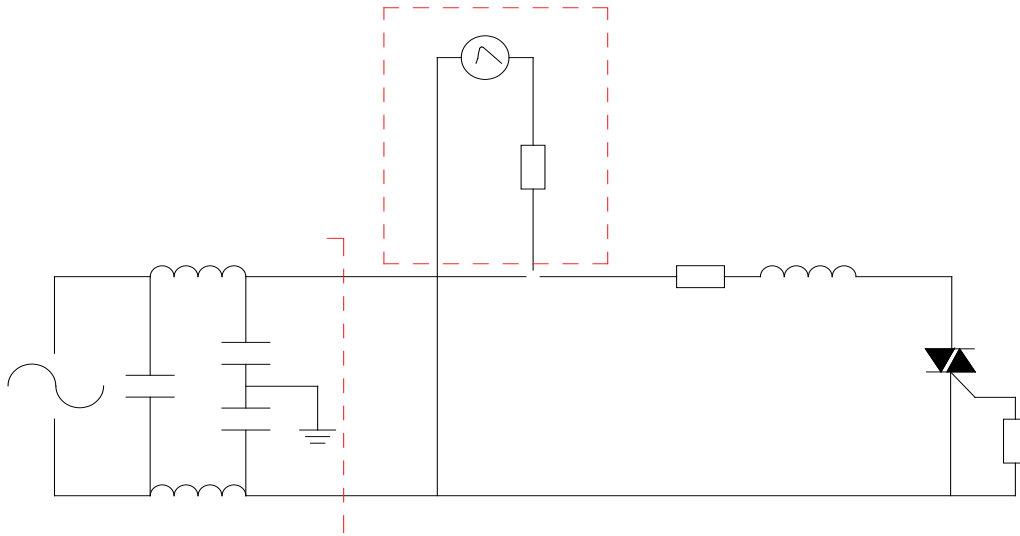


FIG.8: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



**ORDERING INFORMATION**

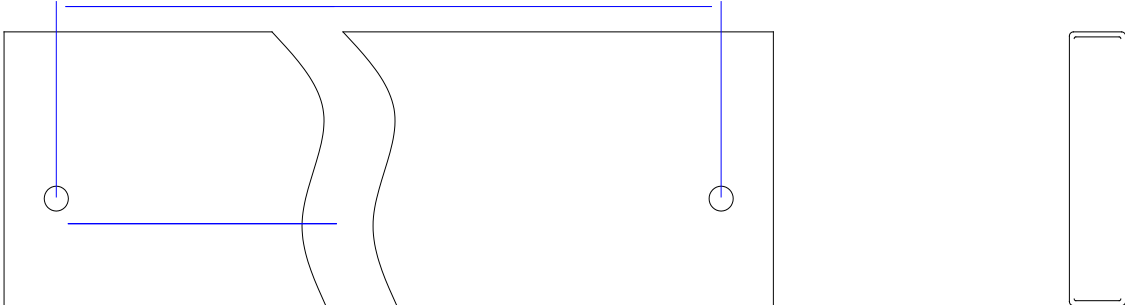
Order cœle	Vdt age V <sub>DRM</sub> /V <sub>RRM</sub> (V)	IGT(mA )	Package	Base q y. (œs)	Deli very rœle
		H- I- J			
JST24E-1200CW	1200	35	TO-263	50	Tube
JST24E-1200CW-TR				800	Tape & Reel

**Docœment Revi si œn Hi st œy**

Date	Revision



DELIVERY MODE



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